

FDD7030BL/FDU7030BL

30V N-Channel PowerTrench⁰ MOSFET

General Description

This N-Channel MOSFET has been designed specifically to improve the overall efficiency of DC/DC converters using either synchronous or conventional switching PWM controllers. It has been optimized for low gate charge, low $R_{DS(ON)}$, fast switching speed and extremely low $R_{DS(ON)}$ in a small package.

Applications

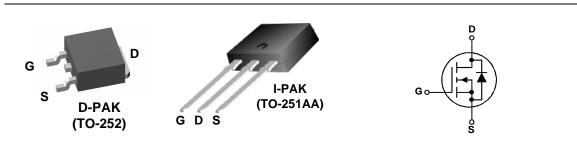
- DC/DC converter
- Motor Drives

Features

• 56 A, 30 V
$$R_{DS(ON)} = 9.5 \text{ m}\Omega @ V_{GS} = 10 \text{ V}$$

 $R_{DS(ON)} = 13 \text{ m}\Omega @ V_{GS} = 4.5 \text{ V}$

- Low gate charge
- Fast Switching
- High performance trench technology for extremely low R_{DS(ON)}



Absolute Maximum Ratings TA=25°C unless otherwise noted

Symbol	Parameter			R	atings	Units
V _{DSS}	Drain-Source Voltage				30	V
V _{GSS}	Gate-Source Voltage				±20	V
l _D	Continuous Drain Curre	nt @T _c =25°C	(Note 3)		56	А
		@T _A =25°C	(Note 1a)		14	
		Pulsed	(Note 1a)		100	
⊃ _D	Power Dissipation	@T _c =25°C	(Note 3)		60	W
		@T _A =25°C	(Note 1a)		2.8	
		@T _A =25°C	(Note 1b)		1.3	
T _J , T _{STG}	Operating and Storage Junction Temperature Range		-5	5 to +175	°C	
Therma	al Characteristics	5				
R _{eJC}			(Note 1)		2.5	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient (Note 1a)		45			
R _{θJA}			(Note 1b)		96	
Packad	e Marking and O	rdering Inf	ormation			
	Marking Devi		ackage	Reel Size	Tape width	Quantity

Device Marking	Device	Package	Reel Size	Tape width	Quantity
 FDD7030BL	FDD7030BL	D-PAK (TO-252)	13"	12mm	2500 units
 FDU7030BL	FDU7030BL	I-PAK (TO-251)	Tube	N/A	75

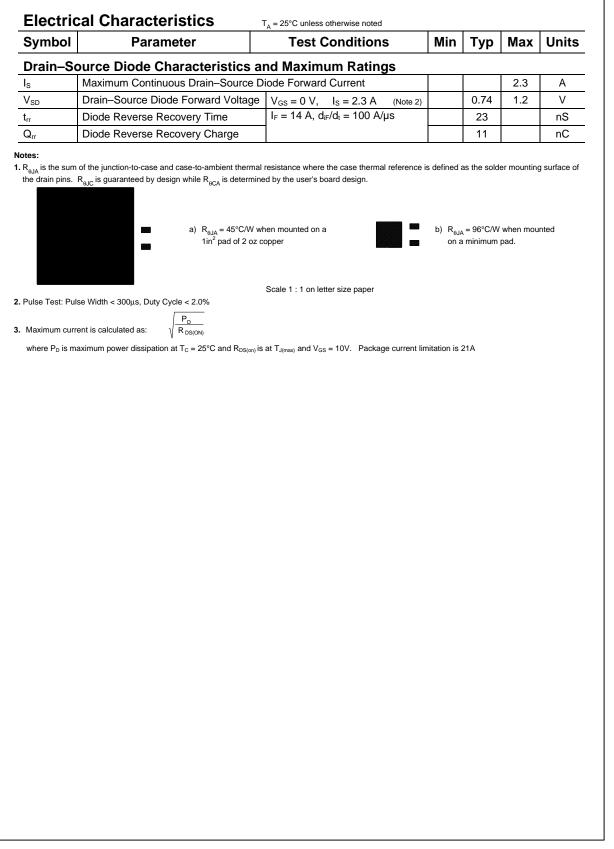
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	Parameter	Test Conditions	Min	Тур	Max	Units
Drain-So	ource Avalanche Ratings (Not	e 2)			•	•
E _{AS}	Drain-Source Avalanche Energy	Single Pulse, $V_{DD} = 15 \text{ V}$, $I_D = 14 \text{ A}$			174	mJ
I _{AS}	Drain-Source Avalanche Current				14	Α
Off Char	acteristics					
BV _{DSS}	Drain–Source Breakdown Voltage	$V_{GS} = 0 V$, $I_{D} = 250 \mu A$	30			V
<u>ΔBVbss</u> ΔTJ	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A,Referenced to 25°C		26		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}$			1	μA
I _{GSS}	Gate–Body Leakage	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			±100	nA
On Char	acteristics (Note 2)					I
	acteristics (Note 2) Gate Threshold Voltage	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$	1	1.8	3	V
$\frac{\Delta V_{GS(th)}}{\Delta T_{J}}$	Gate Threshold Voltage Temperature Coefficient	$v_{DS} = v_{GS}$, $v_D = 250 \ \mu A$ $I_D = 250 \ \mu A$, Referenced to $25^{\circ}C$		-5	5	w mV/°C
R _{DS(on)}	Static Drain–Source On–Resistance			7.5 9.6 11	9.5 13 16	mΩ
I _{D(on)}	On–State Drain Current	$V_{GS} = 10 \text{ V}, V_{DS} = 5 \text{ V}$	50			Α
g _{FS}	Forward Transconductance	$V_{\text{DS}} = 10 \text{ V}, \qquad I_{\text{D}} = 14 \text{ A}$		56		S
Dvnamio	Characteristics					
Ciss	Input Capacitance			1425		pF
C _{oss}	Output Capacitance	$V_{DS} = 15 V$, $V_{GS} = 0 V$,		350		pF
Crss	Reverse Transfer Capacitance	f = 1.0 MHz		150		pF
R _G	Gate Resistance	$V_{OSC} = 15 \text{ mV}, \text{ f} = 1.0 \text{ MHz}$		1.3		pF
Switchin	g Characteristics (Note 2)					
t _{d(on)}	Turn-On Delay Time			11	20	ns
tr	Turn–On Rise Time	$V_{DD} = 15 V, I_D = 1 A,$		9	18	ns
t _{d(off)}	Turn–Off Delay Time	$V_{GS} = 10 \text{ V}, \qquad R_{GEN} = 6 \Omega$		31	50	ns
t _f	Turn–Off Fall Time			13	23	ns
u,	Total Gate Charge			14	20	nC
Q _g		$V_{DS} = 15V, I_D = 14 A, V_{GS} = 5 V$		4		nC
	Gate–Source Charge	$V_{CS} = D V$				

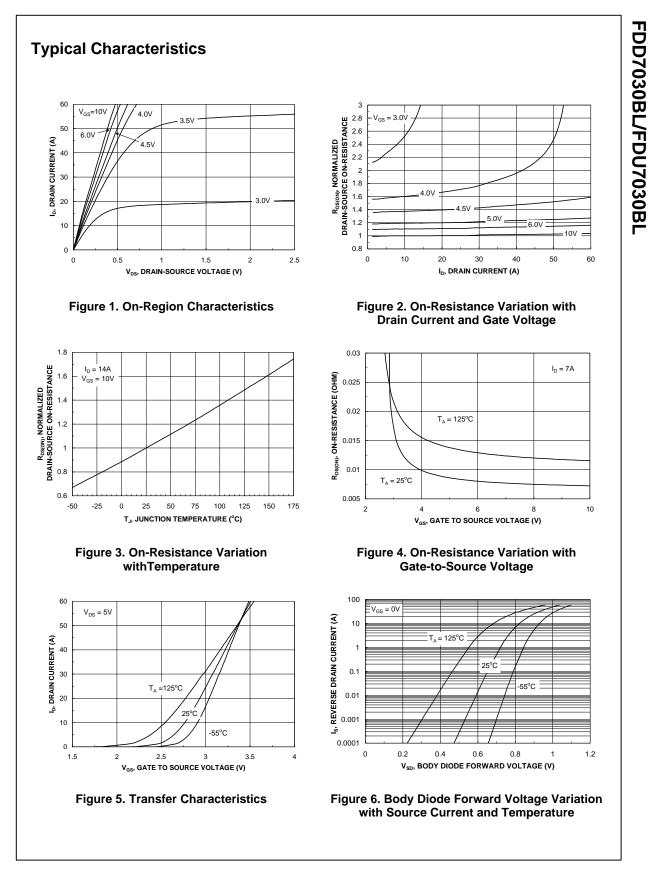
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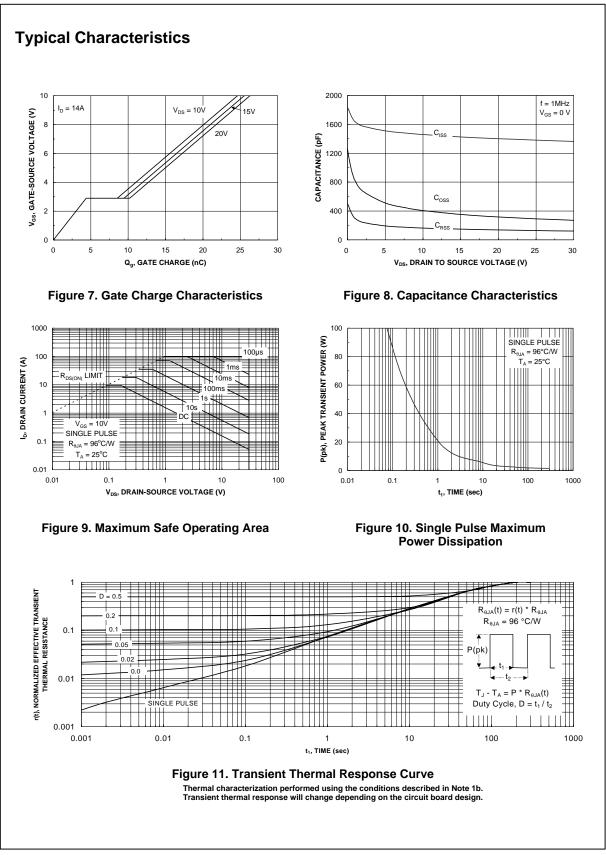


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